

SNx4HC573A 3 ステート出力、オクタール・トランスペアレント D タイプ・ラッチ

1 特長

- 広い動作電圧範囲: 2V~6V
- バス・ラインを直接、または最大 15 の LSTTL 負荷を駆動する大電流 3 ステート出力
- 低い消費電力: $I_{CC} = 80\mu A$ (最大値)
- $t_{pd} = 21ns$ (標準値)
- 5V で $\pm 6mA$ の出力駆動能力
- 低い入力電流: $1\mu A$ (最大値)
- バス配線に適したピン配置

2 アプリケーション

- バッファ・レジスタ
- 双方向バス・ドライバ
- 作業レジスタ

3 概要

SNx4HC573A は、オクタール・トランスペアレント D タイプ・ラッチで、大きい容量性負荷または比較的低いインピーダンスの負荷の駆動用に設計された 3 ステート出力を備えています。

特に、バッファ・レジスタ、I/O ポート、双方向バス・ドライバ、作業レジスタの実装に適しています。

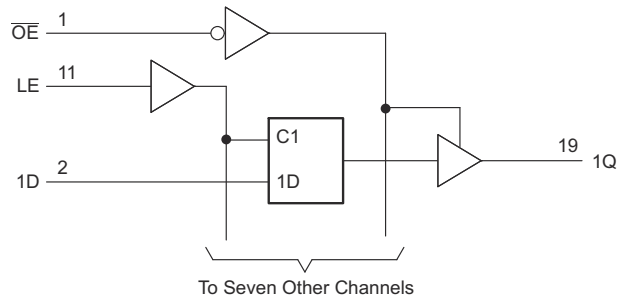
ラッチ・イネーブル (LE) 入力が HIGH のとき、Q 出力はデータ (D) 入力に従います。

LE が LOW のとき、出力はラッチされて、設定されたデータを保持します。

製品情報⁽¹⁾

部品番号	パッケージ	本体サイズ (公称)
SN54HC573AJ	CDIP (20)	26.92mm × 6.92mm
SN54HC573AW	CFP (20)	13.72mm × 6.92mm
SN54HC573AFK	LCCC (20)	8.89mm × 8.89mm
SN74HC573AN	PDIP (20)	25.40mm × 6.35mm
SN74HC573ADW	SOIC (20)	12.80mm × 7.50mm
SN74HC573ADB	SSOP (20)	7.20mm × 5.30mm
SN74HC573APW	TSSOP (20)	5.00mm × 4.40mm

(1) 利用可能なパッケージについては、このデータシートの末尾にある注文情報を参照してください。



To Seven Other Channels

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論理図 (正論理)



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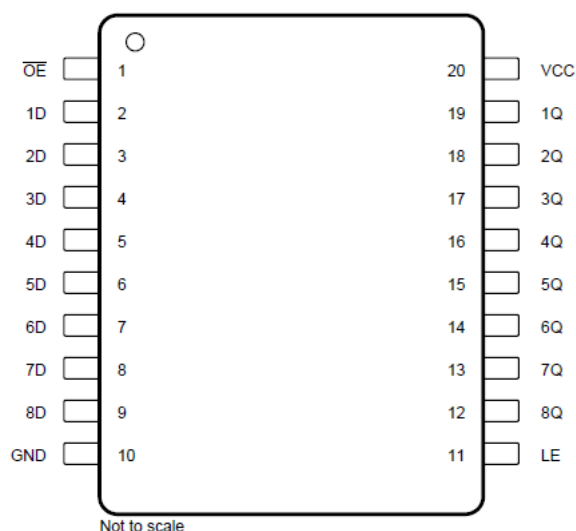
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4 Revision History

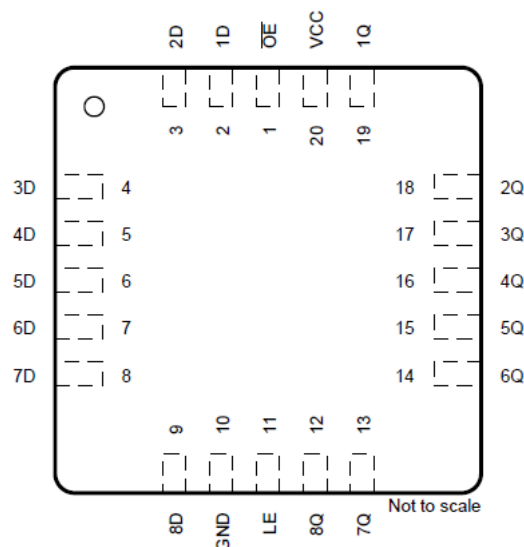
資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision E (September 2003) to Revision F (October 2016)	Page
「ESD 定格」表、「機能説明」セクション、「デバイスの機能モード」セクション、「アプリケーションと実装」セクション、「電源に関する推奨事項」セクション、「レイアウト」セクション、「デバイスおよびドキュメントのサポート」セクション、「メカニカル、パッケージ、および注文情報」セクションを追加。..... 「注文情報」表を削除 (データシートの末尾にある POA を参照)..... - Changed Package thermal impedance, $R_{\theta JA}$, values from 70 to 92.5 (DB), from 58 to 78.3 (DW), from 69 to 49.1 (N), and from 83 to 101.1 (PW).....	1 1 5
Changes from Revision F (October 2016) to Revision G (April 2022)	Page
- Updated ESD ratings table to modern TI standards..... - Changed Package thermal impedance, $R_{\theta JA}$, values from 92.5 to 122.7 (DB), from 78.3 to 109.1 (DW), from 49.1 to 84.6 (N), and from 101.1 to 131.8 (PW).....	4 5

5 Pin Configuration and Functions



DB, DW, J, N, PW, or W Packages
20-Pin SSOP, SOIC, CDIP, PDIP, TSSOP, or CFP
Top View



FK Package
20-Pin LCCC
Top View

Pin Functions

PIN		I/O ⁽¹⁾	DESCRIPTION
NO.	NAME		
1	$\overline{OE}$	I	Output enable
2	1D	I	1D input
3	2D	I	2D input
4	3D	I	3D input
5	4D	I	4D input
6	5D	I	5D input
7	6D	I	6D input
8	7D	I	7D input
9	8D	I	8D input
10	GND	—	Ground
11	LE	I	Latch enable input
12	8Q	O	8Q output
13	7Q	O	7Q output
14	6Q	O	6Q output
15	5Q	O	5Q output
16	4Q	O	4Q output
17	3Q	O	3Q output
18	2Q	O	2Q output
19	1Q	O	1Q output
20	V _{CC}	—	Power pin

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Supply voltage	−0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	V _I < 0 or V _I > V _{CC}		±20 mA
I _{OK}	Output clamp current ⁽²⁾	V _O < 0 or V _O > V _{CC}		±20 mA
I _O	Continuous output current	V _O = 0 to V _{CC}		±35 mA
	Continuous current through V _{CC} or GND			±70 mA
T _J	Junction temperature			150 °C
T _{stg}	Storage temperature	−65		150 °C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±3500
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±1000

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	2	5	6	V
V _{IH}	High-level input voltage	V _{CC} = 2 V	1.5		V
		V _{CC} = 4.5 V	3.15		
		V _{CC} = 6 V	4.2		
V _{IL}	Low-level input voltage	V _{CC} = 2 V		0.5	V
		V _{CC} = 4.5 V		1.35	
		V _{CC} = 6 V		1.8	
V _I	Input voltage	0		V _{CC}	V
V _O	Output voltage	0		V _{CC}	V
t _i	Input transition (rise and fall) time	V _{CC} = 2 V		1000	ns
		V _{CC} = 4.5 V		500	
		V _{CC} = 6 V		400	
T _A	Operating free-air temperature	SN54HC573A	−55	125	°C
		SN74HC573A	−40	85	

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the [Implications of Slow or Floating CMOS Inputs](#) application report (SCBA004).

6.4 Thermal Information

THERMAL METRIC		SN74HC573A				UNIT
		DW (SOIC)	DB (SSOP)	N (PDIP)	PW (TSSOP)	
		20 PINS	20 PINS	20 PINS	20 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	109.1	122.7	84.6	131.8	°C/W
$R_{\theta JC (top)}$	Junction-to-case (top) thermal resistance	76	81.6	72.5	72.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	77.6	77.5	65.3	82.8	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	51.5	46.1	55.3	21.5	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	77.1	77.1	65.2	82.4	°C/W
$R_{\theta JC (bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT	
V _{OH}	V _I = V _{IH} or V _{IL}	I _{OH} = −20 μA	V _{CC} = 2 V	1.9	1.998		V	
			V _{CC} = 4.5 V	4.4	4.499			
			V _{CC} = 6 V	5.9	5.999			
		I _{OH} = −6 mA, V _{CC} = 4.5 V	T _A = 25°C	3.98	4.3			
			SN54HC573A	3.7				
			SN74HC573A	3.84				
			I _{OH} = −7.8 mA, V _{CC} = 6 V	T _A = 25°C	5.48	5.8		
				SN54HC573A	5.2			
				SN74HC573A	5.34			
V _{OL}	V _I = V _{IH} or V _{IL}	I _{OL} = 20 μA	V _{CC} = 2 V		0.002	0.1	V	
			V _{CC} = 4.5 V		0.001	0.1		
			V _{CC} = 6 V		0.001	0.1		
		I _{OL} = 6 mA, V _{CC} = 4.5 V	T _A = 25°C		0.17	0.26		
			SN54HC573A			0.4		
			SN74HC573A			0.33		
			I _{OL} = 7.8 mA, V _{CC} = 6 V	T _A = 25°C		0.15		0.26
				SN54HC573A				0.4
				SN74HC573A				0.33
I _I	V _I = V _{CC} or 0, V _{CC} = 6 V	T _A = 25°C		±0.1	±100	nA		
		SNx4HC573A			±1000			
I _{OZ}	V _O = V _{CC} or 0, V _{CC} = 6 V	T _A = 25°C		±0.01	±0.5	μA		
		SN54HC573A			±10			
		SN74HC573A			±5			
I _{CC}	V _I = V _{CC} or 0, I _O = 0, V _{CC} = 6 V	T _A = 25°C			8	μA		
		SN54HC573A			160			
		SN74HC573A			80			
C _i	V _{CC} = 2 V to 6 V				3	10	pF	

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
C_{pd} Power dissipation capacitance per latch	$T_A = 25^\circ\text{C}$, no load		50		pF

6.6 Timing Requirements

over operating free-air temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
t_w Pulse duration, LE high	$V_{CC} = 2\text{ V}$	$T_A = 25^\circ\text{C}$	80			ns
		SN54HC573A	120			
		SN74HC573A	100			
	$V_{CC} = 4.5\text{ V}$	$T_A = 25^\circ\text{C}$	16			
		SN54HC573A	24			
		SN74HC573A	20			
	$V_{CC} = 6\text{ V}$	$T_A = 25^\circ\text{C}$	14			
		SN54HC573A	20			
		SN74HC573A	17			
t_{su} Setup time, data before LE ↓	$V_{CC} = 2\text{ V}$	$T_A = 25^\circ\text{C}$	50			ns
		SN54HC573A	75			
		SN74HC573A	63			
	$V_{CC} = 4.5\text{ V}$	$T_A = 25^\circ\text{C}$	10			
		SN54HC573A	15			
		SN74HC573A	13			
	$V_{CC} = 6\text{ V}$	$T_A = 25^\circ\text{C}$	9			
		SN54HC573A	13			
		SN74HC573A	11			
t_h Hold time, data after LE ↓	$V_{CC} = 2\text{ V}$	$T_A = 25^\circ\text{C}$	20			ns
		SNx4HC573A	24			
	$V_{CC} = 4.5\text{ V}$		5			
	$V_{CC} = 6\text{ V}$		5			

6.7 Switching Characteristics

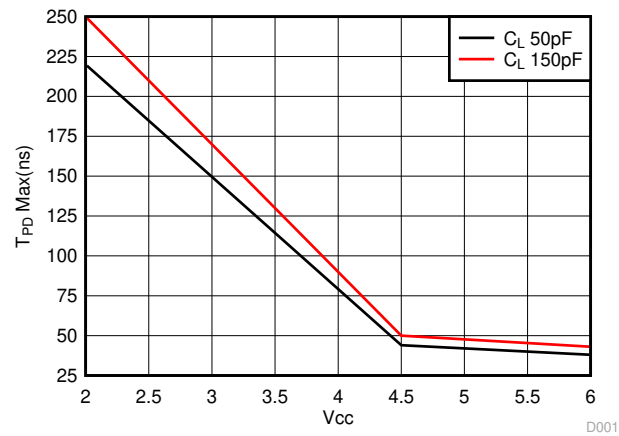
over operating free-air temperature range (unless otherwise noted; see [7-1](#))

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
t_{pd}	$C_L = 50 \text{ pF}$, from D (input) to Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		77	175	ns
			SN54HC573A			265	
			SN74HC573A			220	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		26	35	
			SN54HC573A			53	
			SN74HC573A			44	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		23	30	
			SN54HC573A			45	
			SN74HC573A			38	
	$C_L = 50 \text{ pF}$, from LE (input) to any Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		87	175	
			SN54HC573A			265	
			SN74HC573A			220	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		27	35	
			SN54HC573A			53	
			SN74HC573A			44	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		23	30	
			SN54HC573A			45	
			SN74HC573A			38	
t_{en}	$C_L = 50 \text{ pF}$, from $\overline{OE}$ (input) to any Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		68	150	ns
			SN54HC573A			225	
			SN74HC573A			190	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		24	30	
			SN54HC573A			45	
			SN74HC573A			38	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		21	26	
			SN54HC573A			38	
			SN74HC573A			32	
t_{dis}	$C_L = 50 \text{ pF}$, from $\overline{OE}$ (input) to any Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		47	150	ns
			SN54HC573A			225	
			SN74HC573A			190	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		23	30	
			SN54HC573A			45	
			SN74HC573A			38	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		21	26	
			SN54HC573A			38	
			SN74HC573A			32	

over operating free-air temperature range (unless otherwise noted; see [7-1](#))

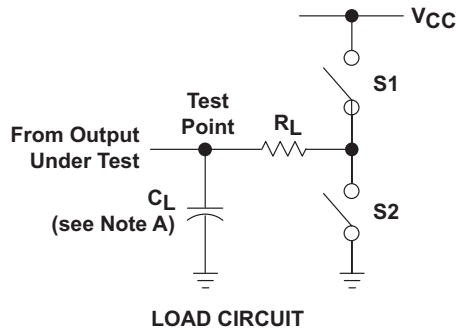
PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
t_t	$C_L = 50 \text{ pF}$ to any Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		28	60	ns
			SN54HC573A			90	
			SN74HC573A			75	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		8	12	
			SN54HC573A			18	
			SN74HC573A			15	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		6	10	
			SN54HC573A			15	
			SN74HC573A			13	
t_{pd}	$C_L = 150 \text{ pF}$, from D (input) to Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		95	200	ns
			SN54HC573A			300	
			SN74HC573A			250	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		33	40	
			SN54HC573A			60	
			SN74HC573A			50	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		21	34	
			SN54HC573A			51	
			SN74HC573A			43	
	$C_L = 150 \text{ pF}$, from LE (input) to any Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		103	225	
			SN54HC573A			335	
			SN74HC573A			285	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		33	45	
			SN54HC573A			67	
			SN74HC573A			57	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		29	40	
			SN54HC573A			60	
			SN74HC573A			50	
t_{en}	$C_L = 150 \text{ pF}$, from $\overline{OE}$ (input) to any Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		85	200	ns
			SN54HC573A			300	
			SN74HC573A			250	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		29	40	
			SN54HC573A			60	
			SN74HC573A			50	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		26	34	
			SN54HC573A			51	
			SN74HC573A			43	
t_t	$C_L = 150 \text{ pF}$ to any Q (output)	$V_{CC} = 2 \text{ V}$	$T_A = 25^\circ\text{C}$		60	210	ns
			SN54HC573A			315	
			SN74HC573A			265	
		$V_{CC} = 4.5 \text{ V}$	$T_A = 25^\circ\text{C}$		17	42	
			SN54HC573A			63	
			SN74HC573A			53	
		$V_{CC} = 6 \text{ V}$	$T_A = 25^\circ\text{C}$		14	36	
			SN54HC573A			53	
			SN74HC573A			45	

6.8 Typical Characteristics

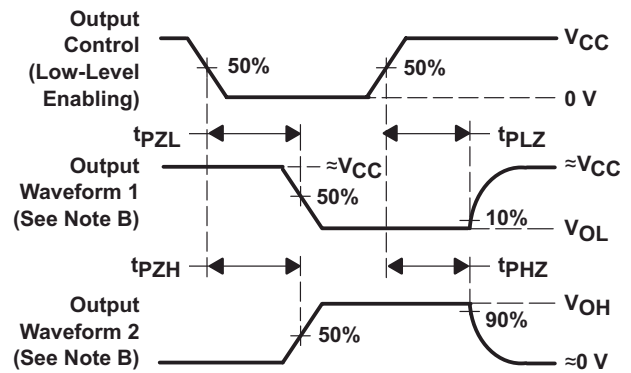
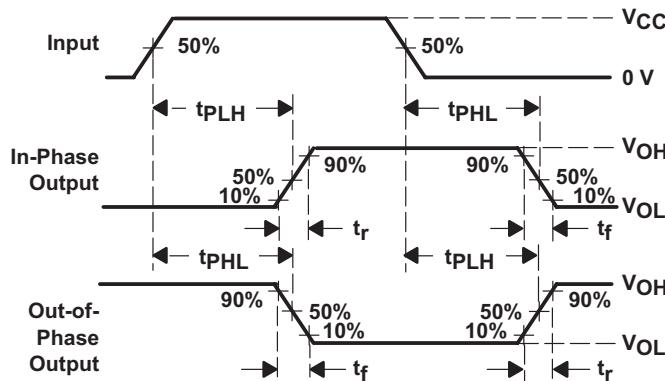
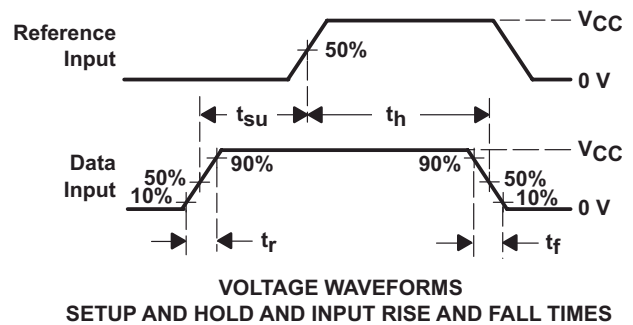
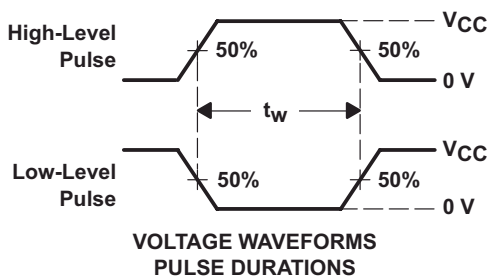


6-1. Maximum Propagation Delay Curves

7 Parameter Measurement Information



PARAMETER	R_L	C_L	S1	S2
t_{en}	1 k Ω	50 pF or 150 pF	Open	Closed
			Closed	Open
t_{dis}	1 k Ω	50 pF	Open	Closed
			Closed	Open
t_{pd} or t_t	--	50 pF or 150 pF	Open	Open



- C_L includes probe and test-fixture capacitance.
- Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1$ MHz, $Z_O = 50 \Omega$, $t_r = 6$ ns, $t_f = 6$ ns.
- The outputs are measured one at a time with one input transition per measurement.
- t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- t_{PZL} and t_{PZH} are the same as t_{en} .
- t_{PLH} and t_{PHL} are the same as t_{pd} .

7-1. Load Circuit and Voltage Waveforms

8 Detailed Description

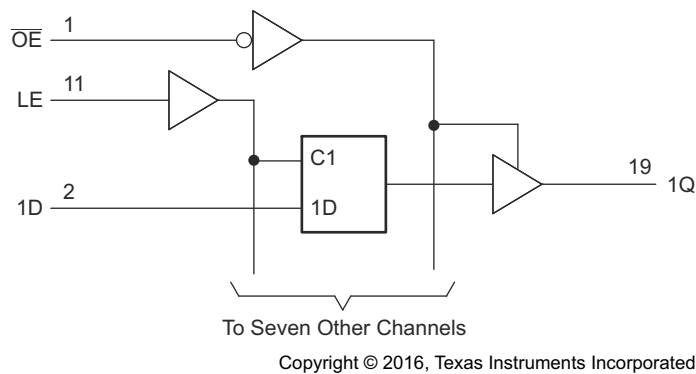
8.1 Overview

The SNx4HC573A devices are octal transparent D-type latches that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. A buffered output-enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ must be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

$\overline{OE}$ does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

8.2 Functional Block Diagram



8-1. Logic Diagram (Positive Logic)

8.3 Feature Description

The SNx4HC573A is a high current 3-state output device which can drive bus lines directly or up to 15 LSTTL loads. It has low power consumption up to 80- μ A maximum I_{CC} . The high speed CMOS family has typical propagation delay of 21 ns with ± 6 -mA output drive at 5 V. The input leakage current is a very low 1- μ A (maximum).

8.4 Device Functional Modes

表 8-1 lists the functional modes of the SNx4HC573A.

表 8-1. Function Table (Each Latch)

INPUTS			OUTPUT
$\overline{OE}$	LE	D	Q
L	H	H	H
L	H	L	L
L	L	X	Q_0
H	X	X	Hi-Z

9 Application and Implementation

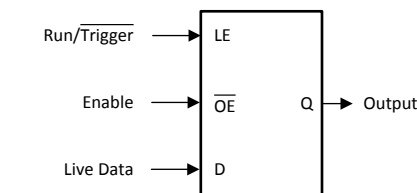
Note

以下のアプリケーション情報は、TI の製品仕様に含まれるものではなく、TI ではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。また、お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

9.1 Application Information

To ensure the high-impedance state during power up or power down, $\overline{OE}$ must be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. $\overline{OE}$ does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state. The SNx4HC573A latches can be used to store 8 bits of data. [図 9-1](#) shows a typical application. A low trigger event latches the output to preserve the event for processing later. With latch input high, this acts as a buffer which follows the live data at the D input when output enable pin held is low.

9.2 Typical Application



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図 9-1. Typical Application Schematic

9.2.1 Design Requirements

The SNx4HC573A device uses CMOS technology and has balanced output drive ($\pm 7.8\text{-mA}$). Take care to avoid bus contention, because it can drive currents that would exceed maximum limits.

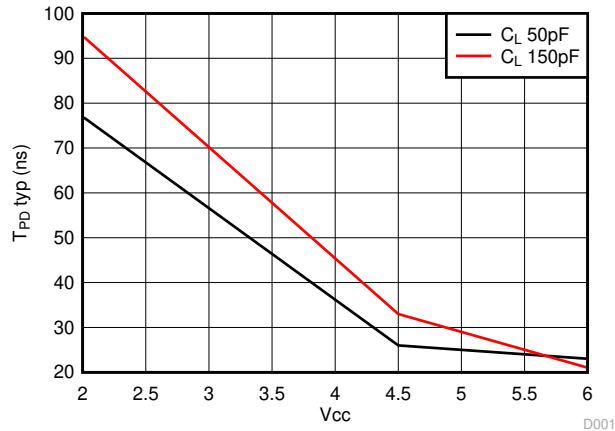
9.2.2 Detailed Design Procedure

Design requirements must adhere to the [セクション 6.3](#) and must never exceed the [セクション 6.1](#).

The inputs must have a ramp time less than input transition time mentioned in the [セクション 6.3](#). Slow inputs can cause oscillations at the output, false triggering, and increased current consumption. TI recommends a Schmitt trigger device like SN74HC14 which can tolerate slower signals.

The inputs and outputs must never exceed V_{CC} to not forward bias the internal ESD diodes. The maximum frequency supported by this device is 28 MHz.

9.2.3 Application Curve



9-2. Typical Propagation Delay Curves

10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the セクション 6.3 table. The total current through Ground or VCC must not exceed ± 70 mA as per セクション 6.1 table.

Each VCC pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends 0.1- μ F capacitor; if there are multiple VCC pins, then TI recommends 0.01- μ F or 0.022- μ F capacitor for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1- μ F and 1- μ F capacitor are commonly used in parallel. The bypass capacitor must be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple-bit logic devices, inputs must never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input and the gate are used, or only 3 of the 4 buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. [Figure 11-1](#) specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, they are tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it disables the output section of the part when asserted. This does not disable the input section of the I/Os, so they cannot float when disabled.

11.2 Layout Example

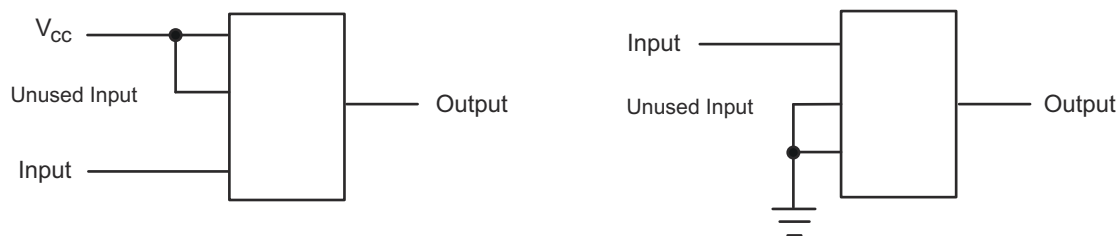


Figure 11-1. Layout Diagram

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

[Implications of Slow or Floating CMOS Inputs](#) (SCBA004)

12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 12-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54HC573A	Click here	Click here	Click here	Click here	Click here
SN74HC573A	Click here	Click here	Click here	Click here	Click here

12.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.4 サポート・リソース

TI E2E™ サポート・フォーラムは、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

リンクされているコンテンツは、該当する貢献者により、現状のまま提供されるものです。これらは TI の仕様を構成するものではなく、必ずしも TI の見解を反映したものではありません。TI の[使用条件](#)を参照してください。

12.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

すべての商標は、それぞれの所有者に帰属します。

12.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-8512801VRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8512801VR A SNV54HC573AJ
5962-8512801VRA.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8512801VR A SNV54HC573AJ
85128012A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85128012A SNJ54HC 573AFK
8512801RA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512801RA SNJ54HC573AJ
8512801SA	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512801SA SNJ54HC573AW
JM38510/65406BRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65406BRA
JM38510/65406BRA.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65406BRA
M38510/65406BRA	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65406BRA
SN54HC573AJ	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC573AJ
SN54HC573AJ.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC573AJ
SN74HC573ADBR	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A
SN74HC573ADBR.A	Active	Production	SSOP (DB) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A
SN74HC573ADW	Obsolete	Production	SOIC (DW) 20	-	-	Call TI	Call TI	-40 to 85	HC573A
SN74HC573ADWR	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A
SN74HC573ADWR.A	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A
SN74HC573ADWRG4	Active	Production	SOIC (DW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A
SN74HC573AN	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC573AN
SN74HC573AN.A	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC573AN
SN74HC573ANE4	Active	Production	PDIP (N) 20	20 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC573AN
SN74HC573APWR	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A
SN74HC573APWR.A	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74HC573APWRG4	Active	Production	TSSOP (PW) 20	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC573A
SN74HC573APWT	Obsolete	Production	TSSOP (PW) 20	-	-	Call TI	Call TI	-40 to 85	HC573A
SNJ54HC573AFK	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85128012A SNJ54HC 573AFK
SNJ54HC573AFK.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	85128012A SNJ54HC 573AFK
SNJ54HC573AJ	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512801RA SNJ54HC573AJ
SNJ54HC573AJ.A	Active	Production	CDIP (J) 20	20 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512801RA SNJ54HC573AJ
SNJ54HC573AW	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512801SA SNJ54HC573AW
SNJ54HC573AW.A	Active	Production	CFP (W) 20	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	8512801SA SNJ54HC573AW

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF SN54HC573A, SN54HC573A-SP, SN74HC573A :

- Catalog : [SN74HC573A](#), [SN54HC573A](#)
- Automotive : [SN74HC573A-Q1](#), [SN74HC573A-Q1](#)
- Military : [SN54HC573A](#)
- Space : [SN54HC573A-SP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military - QML certified for Military and Defense Applications
- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC573ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74HC573ADWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HC573APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC573ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74HC573ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74HC573APWR	TSSOP	PW	20	2000	356.0	356.0	35.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
85128012A	FK	LCCC	20	55	506.98	12.06	2030	NA
8512801SA	W	CFP	20	25	506.98	26.16	6220	NA
SN74HC573AN	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC573AN.A	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC573ANE4	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54HC573AFK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC573AFK.A	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC573AW	W	CFP	20	25	506.98	26.16	6220	NA
SNJ54HC573AW.A	W	CFP	20	25	506.98	26.16	6220	NA

GENERIC PACKAGE VIEW

FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

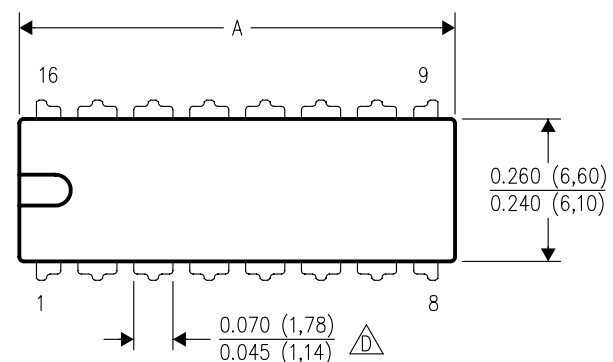


4229370VA\

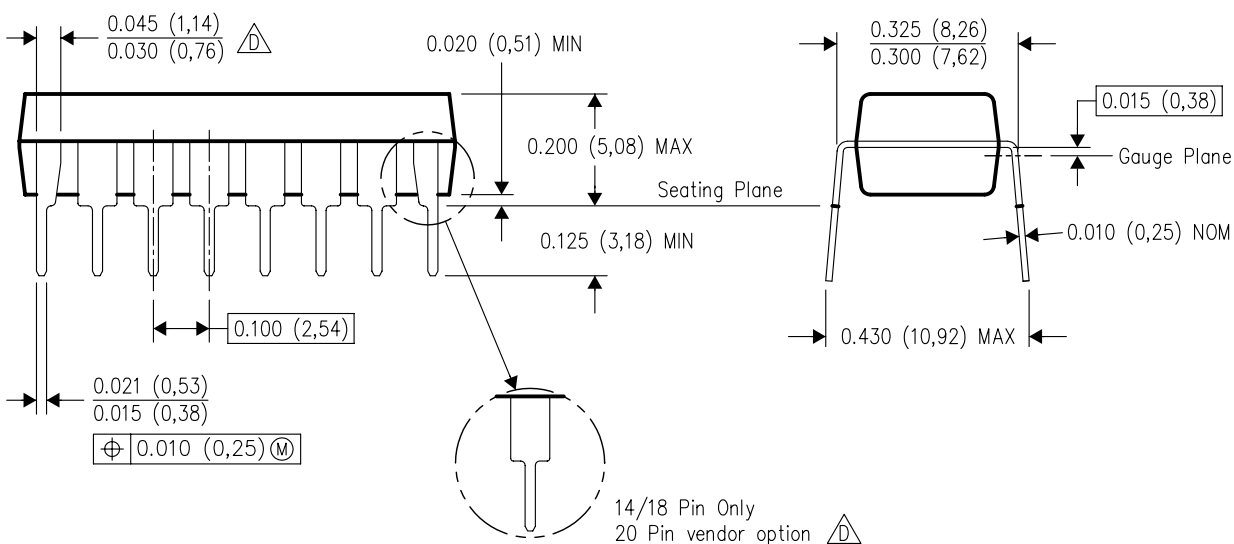
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



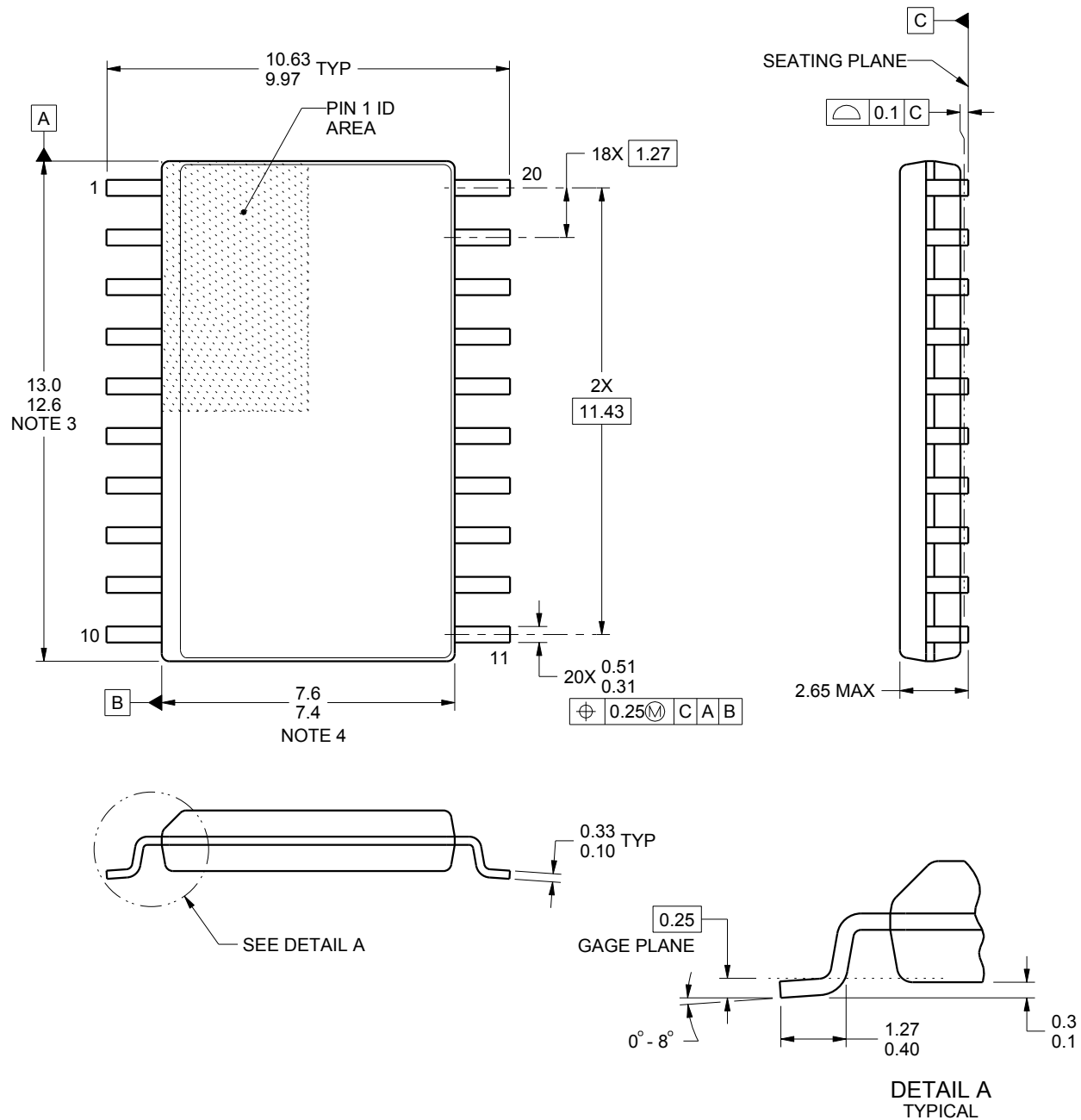
PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.



4220724/A 05/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

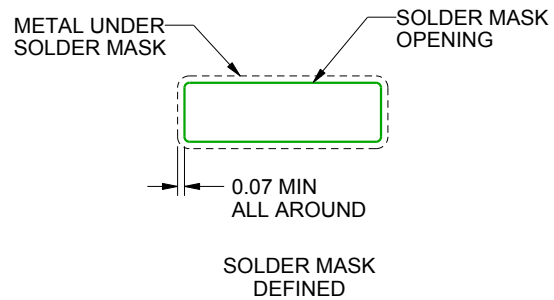
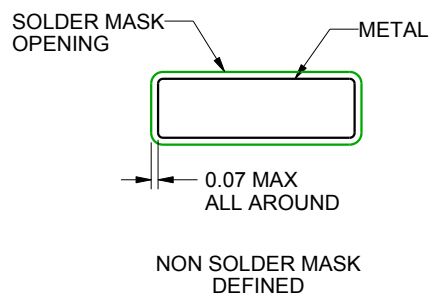
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within Mil-Std 1835 GDFP2-F20



4220206/A 02/2017

NOTES:

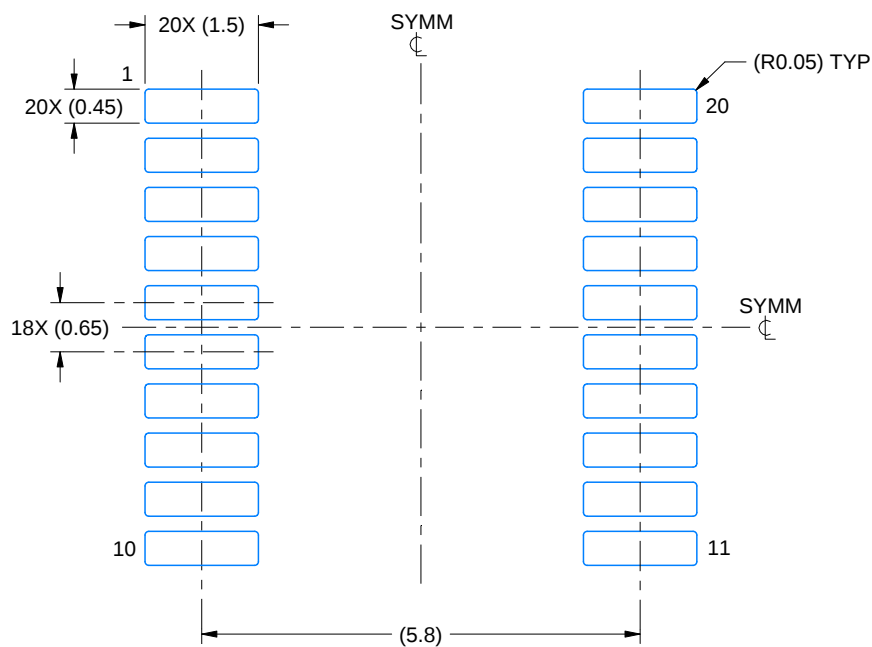
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

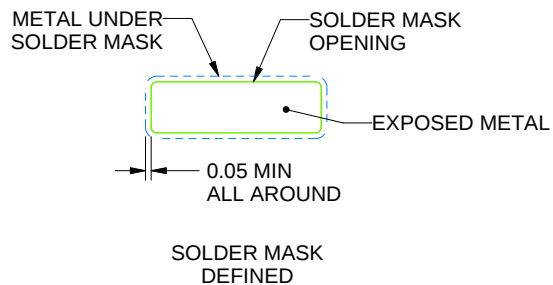
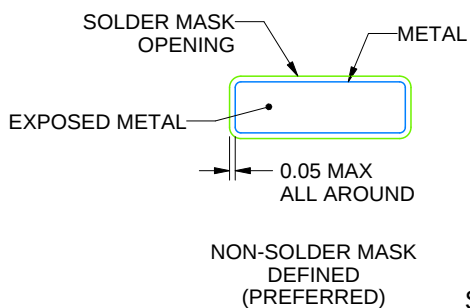
PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220206/A 02/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE

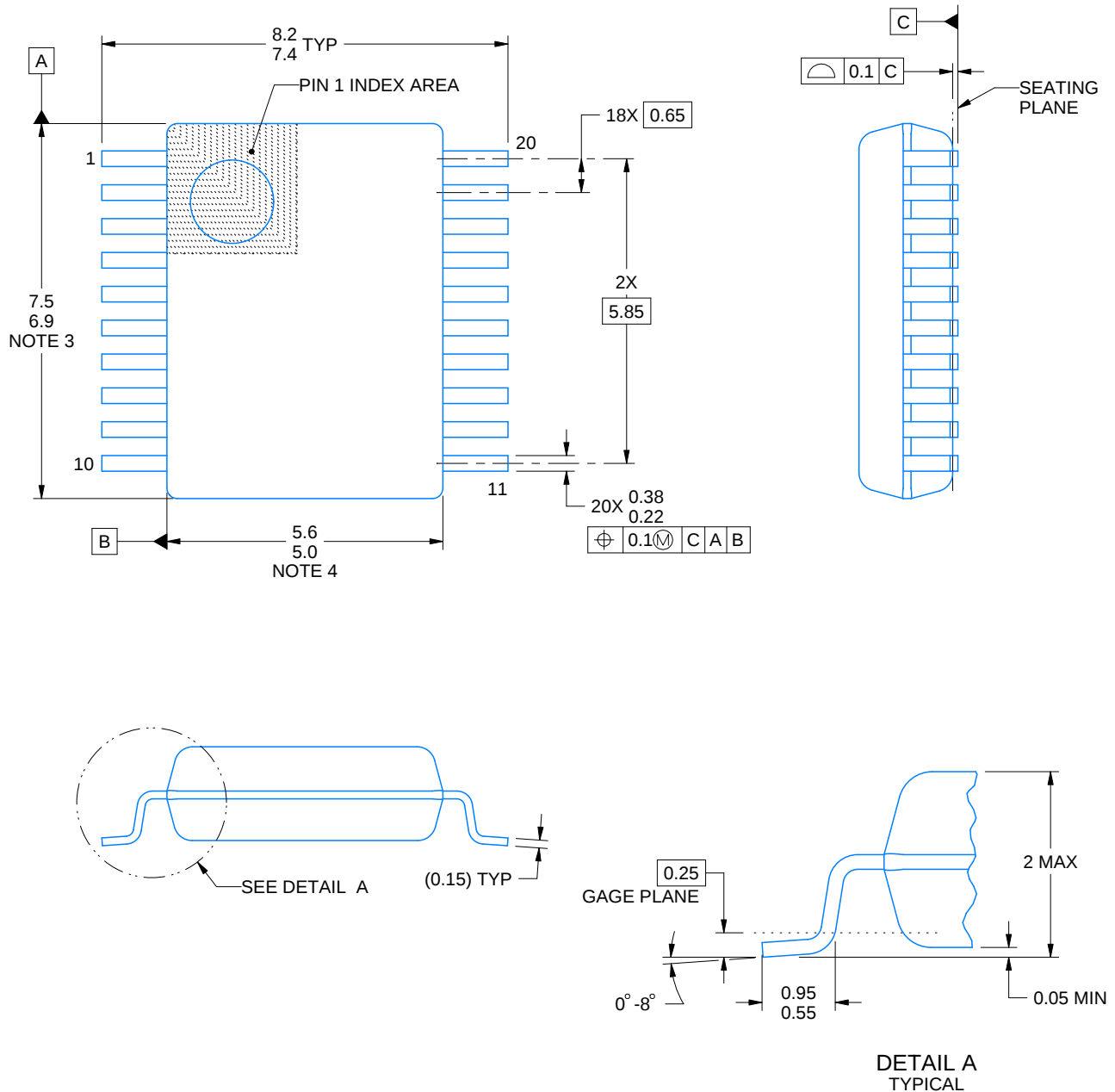
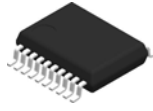


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220206/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



4214851/B 08/2019

NOTES:

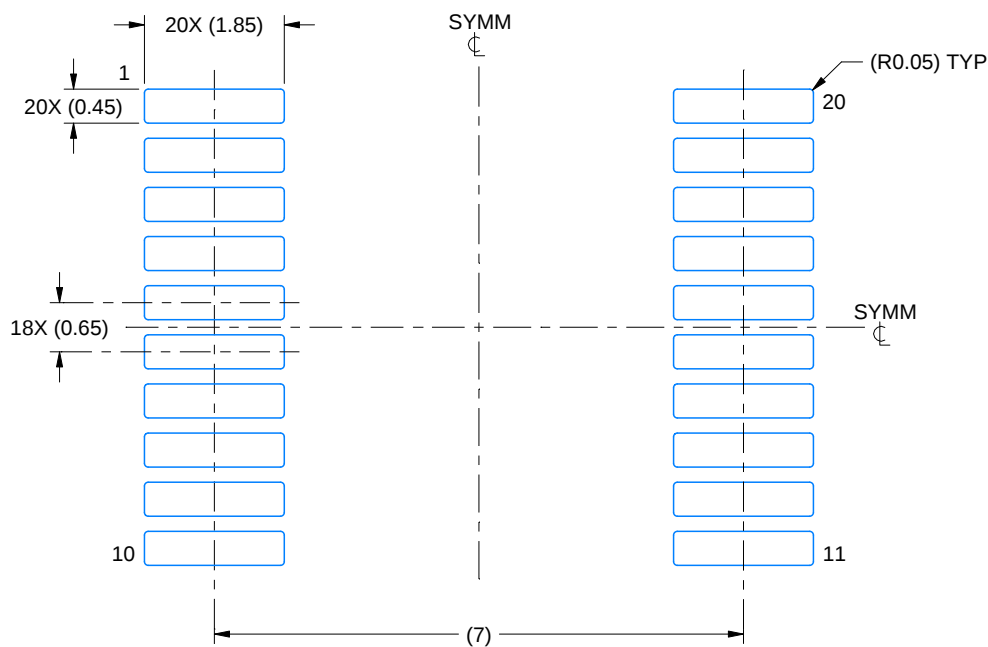
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

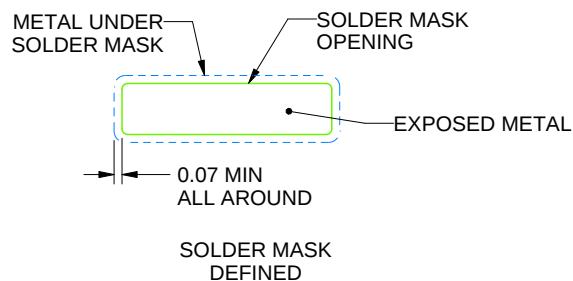
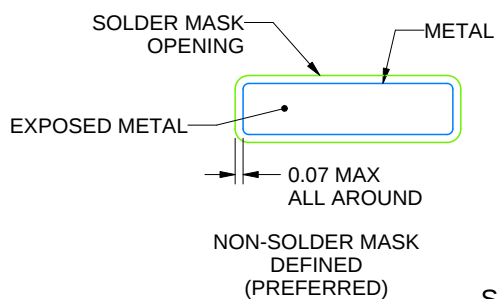
DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4214851/B 08/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

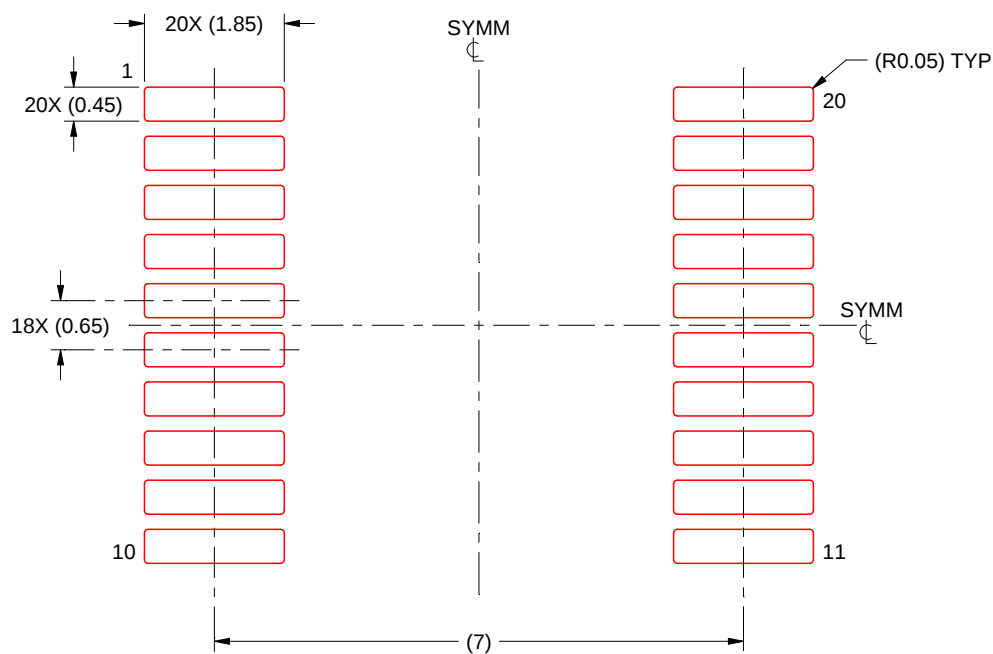
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4214851/B 08/2019

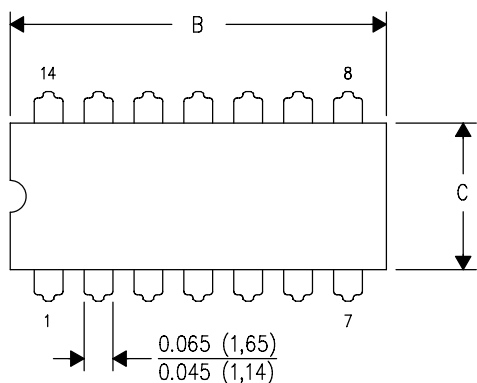
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

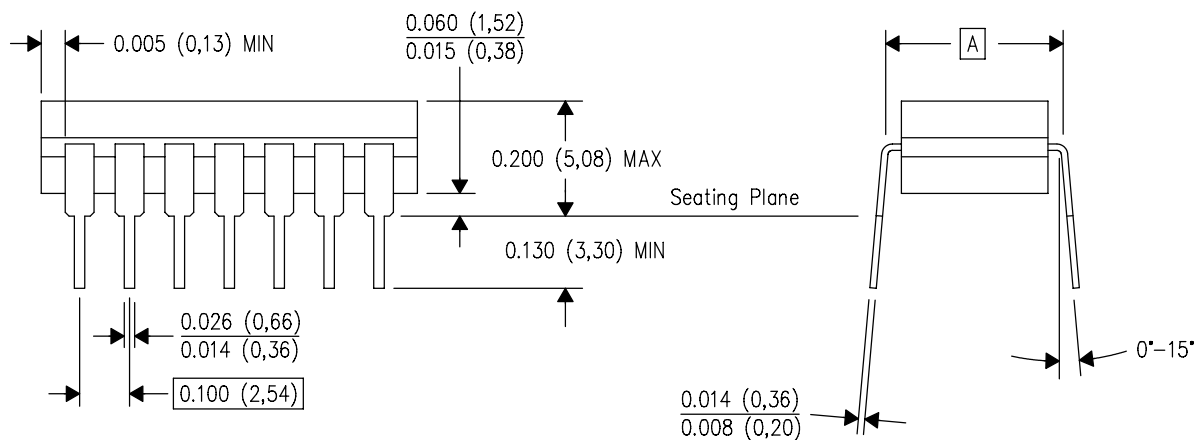
J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



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- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

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